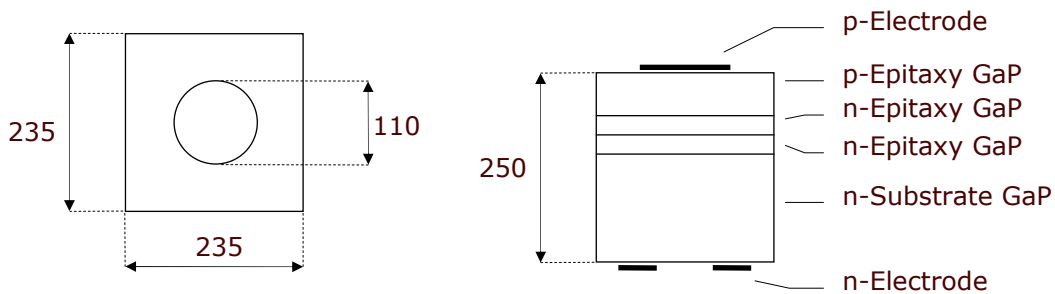


**YELLOW-GREEN**      **Item No.: 160622**

1. This specification applies to GaP / GaP LED Chips
2. Structure
  - 2.1 Mesa structure
  - 2.2 Electrodes                      p-side (anode)      Au alloy  
   n-side (cathode)      Au alloy
3. Outlines (dimensions in microns)



Wire bond contacts can also be square

4. Electrical and optical characteristics (T=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Forward voltage	$V_F$	$I_F = 2 \text{ mA}$		1,95	2,20	V
Reverse current	$I_R$	$V_R = 5 \text{ V}$			10	$\mu\text{A}$
Luminous intensity *	$I_V$	$I_F = 2 \text{ mA}$	500	700		$\mu\text{cd}$
Peak wavelength	$\lambda_P$	$I_F = 2 \text{ mA}$		568		nm

\* On request, wafers will be delivered according to luminous intensity classes  
Brightness measurement at OSA on gold plate

5. Packing
  - Dice on adhesive film with 1) wire bond side on top  
2) back contact on top
6. Labeling

Type	Lot No.	$I_V$ typ min max	Quantity
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